

/ Descriptions

Silicon NPN transistor in a TO-18 Plastic Package.

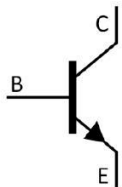
/ Features

High breakdown voltage, excellent high frequency Characteristic.

/ Applications

High-definition CRT display, color TV chroma output and high breakdown voltage driver.

/ Equivalent Circuit



/ Pinning



PIN1 Emitter PIN 2 Collector PIN 3 Base

/ h_{FE} Classifications & Marking

h_{FE} Classifications Symbol	C	O	E	F
h_{FE} Range	40 80	60 120	100 200	160 320

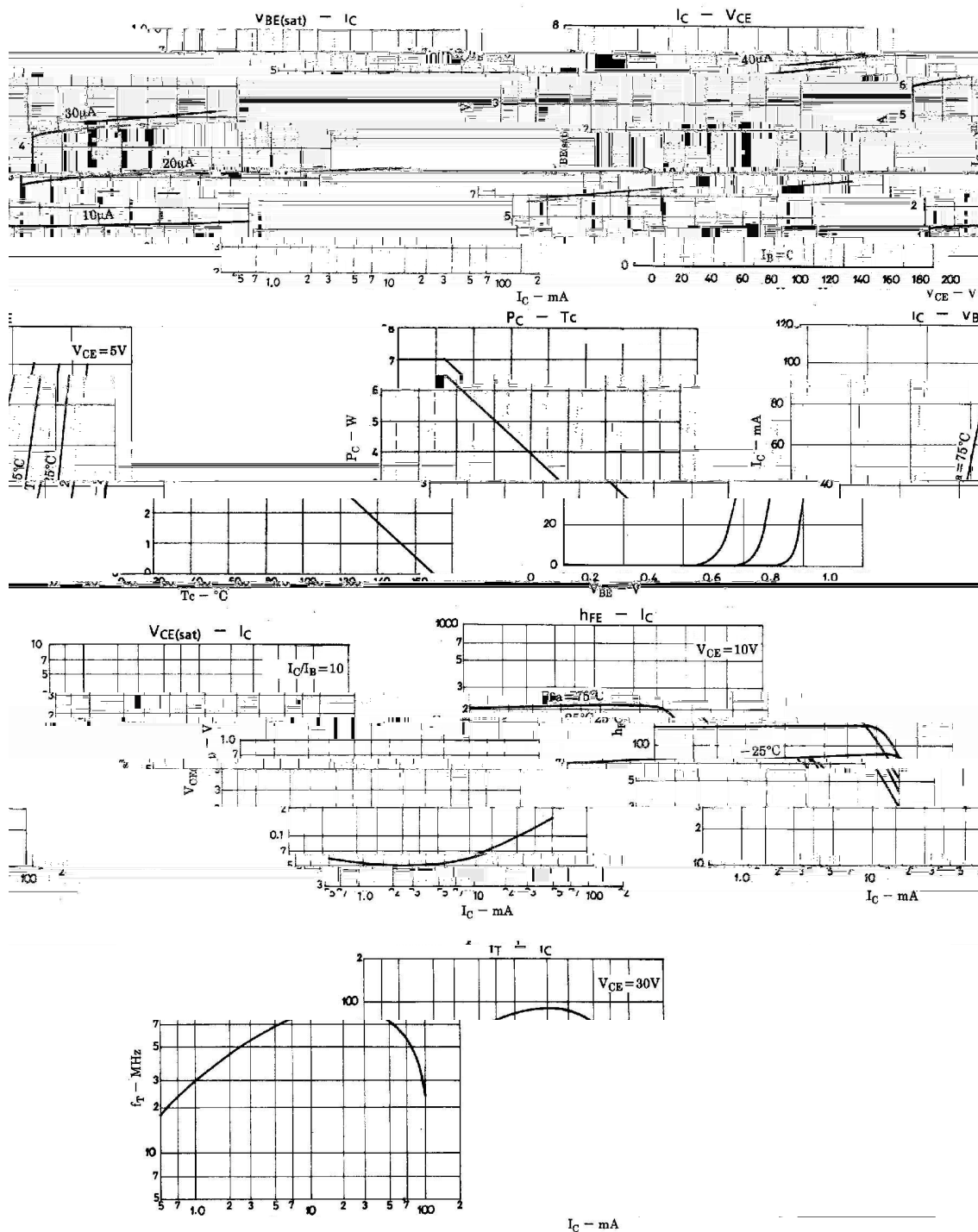
/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	300	V
Collector to Emitter Voltage	V_{CEO}	300	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current - Continuous	I_C	100	mA
Collector Current – Continuous(Pulse)	I_{cp}	200	mA
Collector Power Dissipation	P_C	1.2	W
Collector Power Dissipation	$P_C(T_c=25)$	7.0	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

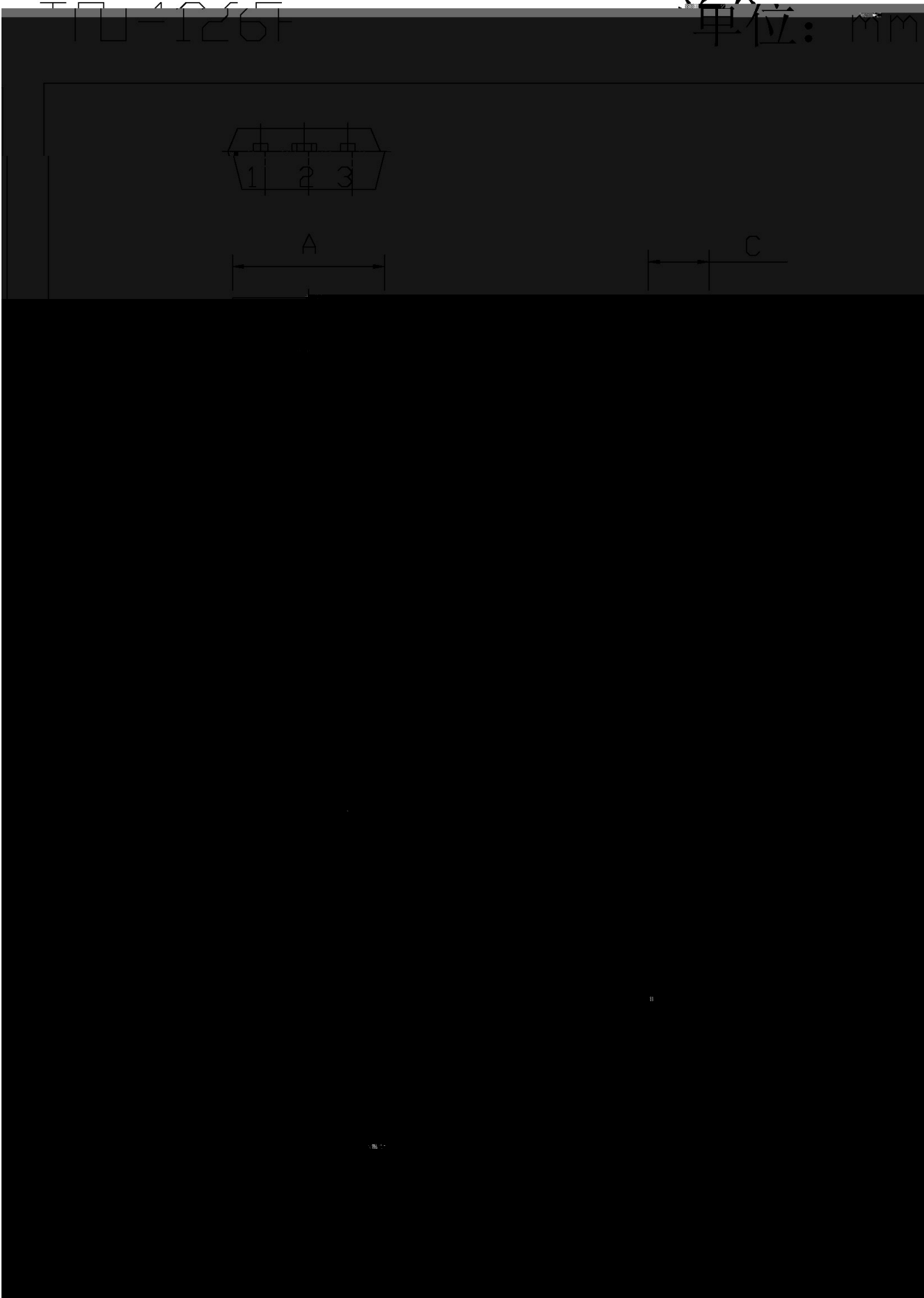
/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Base Breakdown Voltage	V_{CBO}	$I_C=10\mu A$ $I_E=0$	300			V
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C=1.0mA$ $I_B=0$	300			V
Emitter to Base Breakdown Voltage	V_{EBO}	$I_E=10\mu A$ $I_C=0$	5.0			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=200V$ $I_E=0$			0.1	μA
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=4.0V$ $I_C=0$			0.1	μA
DC Current Gain	h_{FE}	$V_{CE}=10V$ $I_C=10mA$	40		320	
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=20mA$ $I_B=2.0mA$			0.6	V
Base to Emitter Voltage	$V_{BE(sat)}$	$I_C=20mA$ $I_B=2.0mA$			1.0	V
Transition Frequency	f_T	$V_{CE}=30V$ $I_C=10mA$		70		MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=30V$ $f=1.0MHz$ $I_E=0$		2.6		pF
Reverse Transfer Capacitance	C_{re}	$V_{CB}=30V$ $f=1.0MHz$		1.8		pF

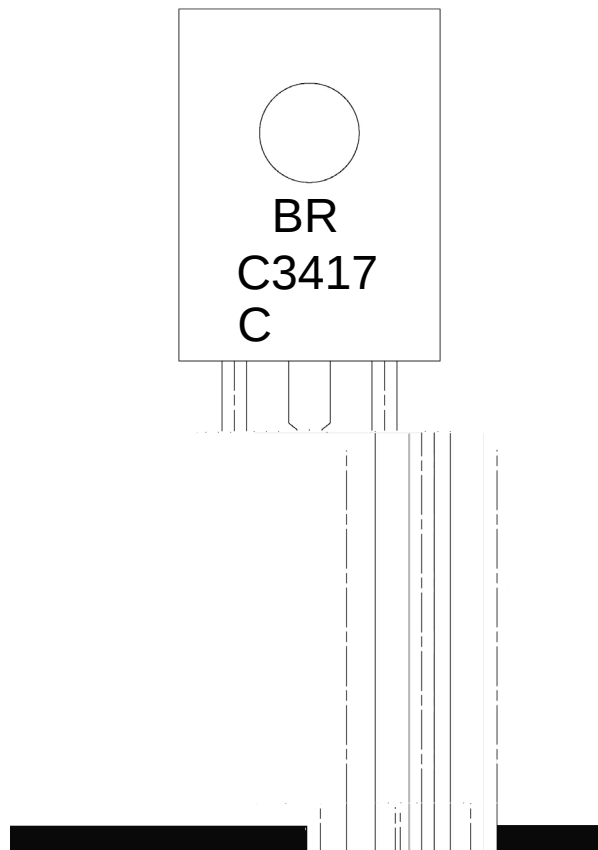
/ Electrical Characteristic Curve



/ Package Dimensions



/ Marking Instructions



Note:

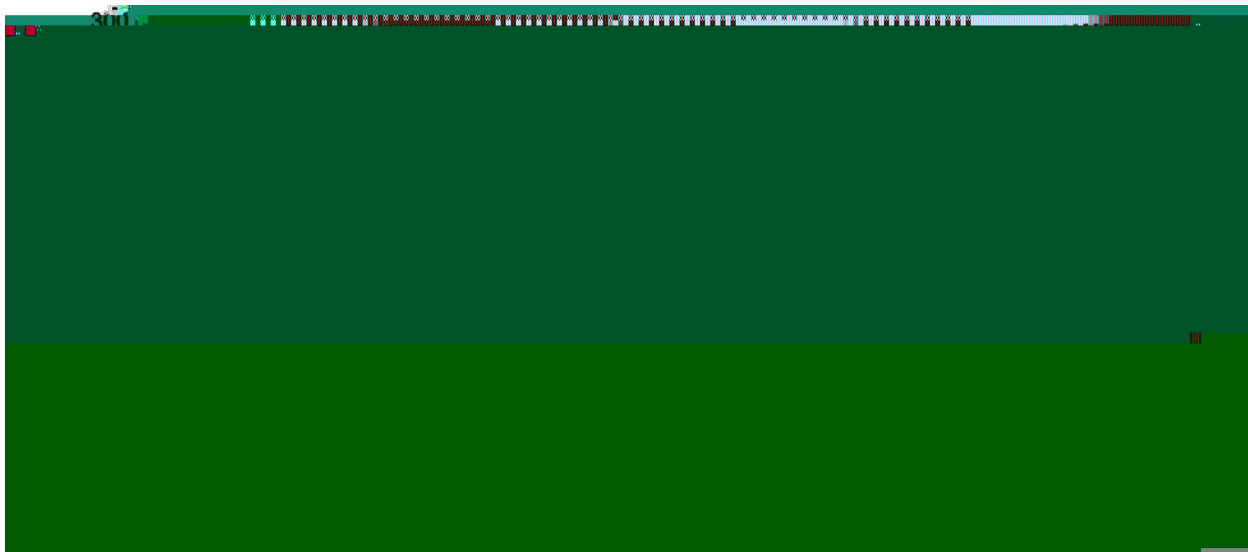
BR: Company Code

C3417: Product Type.

C: h_{FE} Classifications Symbol

***: Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



Note:

- | | | | | | |
|---|-----|-----|----|----------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 255 | 5 | 5 | 0.5sec; | 2.Peak Temp.:255 5 , Duration:5 0.5sec. |
| 3 | | | 2 | 10 /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

270 5 10 1 sec. Temp.:270±5 Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	只 套管	套管 盒	只 盒	盒 箱	只 箱	套管	盒	箱

/ TUBE

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	只 套管	套管 盒	只 盒	盒 箱	只 箱	套管	盒	箱

/ Notices